



ZXT13P12DE6

12V PNP LOW SATURATION SWITCHING TRANSISTOR IN SOT26

Features

- BV_{CEO} > -12V
- I_C = -4A Continuous Collector Current
- I_{CM} = -15A Peak Pulse Current
- $R_{CE(sat)} = 37m\Omega$ for a Low Equivalent On-Resistance
- Low Saturation Voltage of <-90mV max @ -1A
- hFE Characterized up to -15A for High Current Gain Hold-Up
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

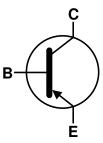
- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
 Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.015 grams (Approximate)

Applications

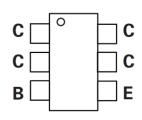
- DC-DC Converters
- Power Management Functions
- Power Switches
- Motor Control







Device Symbol



Pin-Out Top

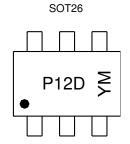
Ordering Information (Notes 4)

| Product | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|---------------|---------|--------------------|-----------------|-------------------|
| ZXT13P12DE6TA | P12D | 7 | 8 | 3,000 |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



P12D = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: C = 2015) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

| | Year | 201 | 5 | 2016 | 2017 | 2018 | 2019 | 2020 | 202 | 1 20 |)22 | 2023 | 2024 | 2025 |
|---|-------|-----|-----|------|------|------|------|------|-----|--------|-----|------|------|------|
| | Code | С | | D | Е | F | G | Н | - | , | J | K | L | М |
| Ī | Month | 1 | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| | Code | | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V_{CBO} | -20 | V |
| Collector-Emitter Voltage | V _{CEO} | -12 | V |
| Emitter-Base Voltage | V _{EBO} | -7.5 | V |
| Base Current | I _B | -500 | mA |
| Continuous Collector Current | Ic | -4 | A |
| Peak Pulse Collector Current | I _{CM} | -15 | Α |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Value | Unit | |
|---|-----------------------------------|-------------------|-------------|------------|--|
| Power Dissipation | (Note 5) | D | 1.1 8.8 | W mW/°C | |
| Linear Derating Factor | (Note 6) | PD | 1.7 13.6 | | |
| Thermal Resistance, Junction to Ambient | (Note 5) | Б | 113 | | |
| Thermal nesistance, Junction to Ambient | (Note 6) | $R_{\theta JA}$ | 73 | °C/W | |
| Thermal Resistance, Junction to Lead (Note 7) | | R ₀ JL | 18.61 | | |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C | | |

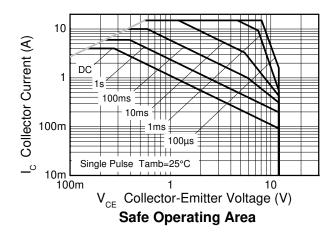
ESD Ratings (Note 8)

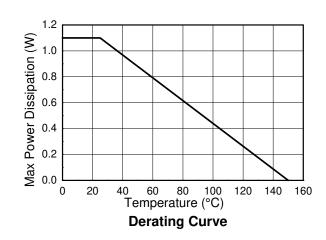
| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | С |

Notes:

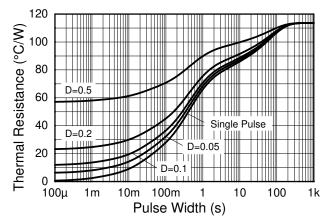
- 5. For a device mounted with collector leads on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is measured at $t \le 5$ seconds.
- 7. Thermal resistance from junction to solder-point (at the end of the collector leads).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information









Transient Thermal Impedance

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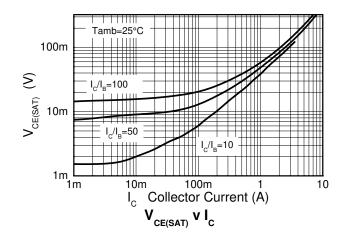
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

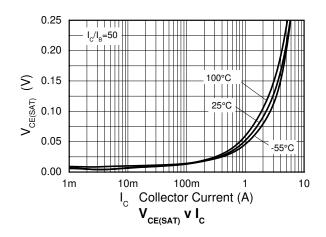
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|----------------------|------|------|------|------|---|--|
| OFF CHARACTERISTICS | | | | | | | |
| Collector-Base Breakdown Voltage | BV_CBO | -20 | -33 | | V | $I_C = -100\mu A$ | |
| Collector-Emitter Breakdown Voltage (Note 9) | BV _{CEO} | -12 | -25 | _ | V | I _C = -10mA | |
| Emitter-Base Breakdown Voltage | BV _{EBO} | -7.5 | -8.5 | _ | V | $I_E = -100 \mu A$ | |
| Collector-Base Cut-Off Current | I _{CBO} | _ | | -100 | nA | V _{CB} = -16V | |
| Emitter Cut-Off Current | I _{EBO} | _ | | -100 | nA | V _{EB} = -6V | |
| Collector-Emitter Cut-Off Current | I _{CES} | _ | | -100 | nA | V _{CES} = -16V | |
| ON CHARACTERISTICS (Note 9) | | | | | | | |
| | | 300 | 500 | | | $I_C = -10 \text{mA}, V_{CE} = -2 \text{V}$ | |
| DC Current Gain | h | 300 | 450 | 900 | | $I_C = -1A$, $V_{CE} = -2V$ | |
| Do Guiterit Gairi | h _{FE} | 200 | 300 | | | $I_C = -4A, V_{CE} = -2V$ | |
| | | 20 | 30 | _ | _ | $I_C = -15A, V_{CE} = -2V$ | |
| | | _ | -7.5 | -10 | | $I_C = -100 \text{mA}, I_B = -10 \text{mA}$ | |
| | | _ | -68 | -90 | mV | $I_C = -1A$, $I_B = -10mA$ | |
| Collector-Emitter Saturation Voltage | V _{CE(sat)} | _ | -135 | -175 | | $I_C = -3A$, $I_B = -50mA$ | |
| | | _ | -200 | -250 | | $I_C = -4A$, $I_B = -50mA$ | |
| | | _ | -150 | -175 | | $I_C = -4A$, $I_B = -400mA$ | |
| Base-Emitter Saturation Voltage | V _{BE(sat)} | _ | | -1.0 | V | $I_C = -4A$, $I_B = -50mA$ | |
| Base-Emitter Turn-On Voltage | V _{BE(on)} | _ | | -0.9 | V | $I_C = -4A$, $V_{CE} = -2V$ | |
| SMALL SIGNAL CHARACTERISTICS | | | | | | | |
| Current Gain-Bandwidth Product | f_T | _ | 55 | | MHz | $V_{CE} = -10V$, $I_{C} = -50mA$, $f = 50MHz$ | |
| Output Capacitance | C_{obo} | _ | 115 | | рF | $V_{CB} = -10V$, $f = 1MHz$ | |
| Turn-On Time | t _(on) | _ | 70 | _ | ns | $V_{CC} = -10V, I_C = -3A$ | |
| Turn-Off Time | t _(off) | _ | 265 | _ | ns | $I_{B1} = I_{B2} = -60 \text{mA}$ | |

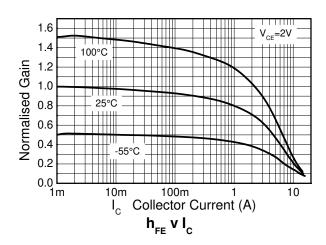
Note: 9. Measured under pulsed conditions; pulse width \leq 300 μ s, duty cycle \leq 2%.

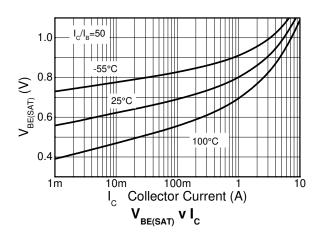


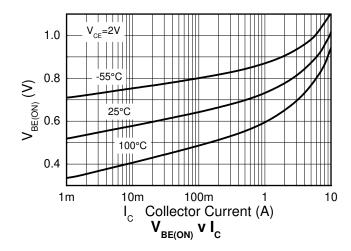
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)







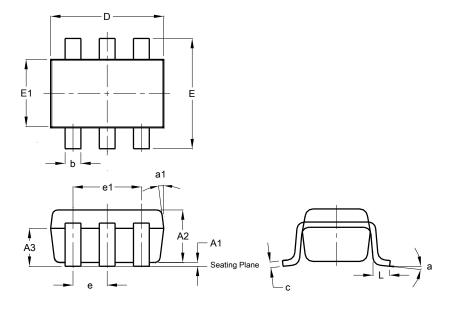






Package Outline

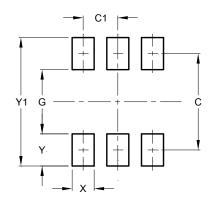
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



| SOT26 | | | | | | | |
|-------|----------------------|------|------|--|--|--|--|
| Dim | Min | Max | Тур | | | | |
| A1 | 0.013 | 0.10 | 0.05 | | | | |
| A2 | 1.00 | 1.30 | 1.10 | | | | |
| А3 | 0.70 | 0.80 | 0.75 | | | | |
| b | 0.35 | 0.50 | 0.38 | | | | |
| С | 0.10 | 0.20 | 0.15 | | | | |
| D | 2.90 | 3.10 | 3.00 | | | | |
| е | - | - | 0.95 | | | | |
| e1 | - | - | 1.90 | | | | |
| Е | 2.70 | 3.00 | 2.80 | | | | |
| E1 | 1.50 | 1.70 | 1.60 | | | | |
| L | 0.35 | 0.55 | 0.40 | | | | |
| а | - | - | 8° | | | | |
| a1 | - | - | 7° | | | | |
| All | All Dimensions in mm | | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| С | 2.40 |
| C1 | 0.95 |
| G | 1.60 |
| Х | 0.55 |
| Y | 0.80 |
| Y1 | 3.20 |



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